Attorney's Docket 071469-0273248 Client Reference: PC0033AREG DEC 0.5 2003

DEC 0 9 2003 TC 1700

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of:

Confirmation Number: 8536

WAYNE L JOHNSON ET AL.

Group Art Unit: 1753

Application No.: 10/076,099

Filed: February 15, 2002

Examiner: Rodney G. McDonald

For: Pl

PULSED PLASMA PROCESSING METHOD AND APPARATUS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

-AMENDMENT/RESPONSE-TRANSMITTAL

Transmitted herewith is an amendment/response for this application.

FEES

The fee for claims and extension of time (37 C.F.R. 1.16 and 1.17) has been calculated as shown below:

	CLAIMS					<u>-</u>					
	REMAINING AFTER AMENDMENT	HIGHEST NO. PREVIOUSLY PAID FOR		PRESENT EXTRA		RATE			ADDIT. FEE		
TOTAL	27	_	26	=	1	X	\$	18.00	=	\$	18.00
INDEP.	3		3	=	0	X	\$	86.00	=	\$	0.00
FIRST PRESENTATION OF MULTIPLE DEP. CLAIM + \$ 290.00									=	\$	0.00
TOTAL ADDITIONAL CLAIM FEE										\$	18.00
GRAND TOTAL										\$	18.00

FEE PAYMENT

Authorization is hereby made to charge the amount of \$18.00 to Deposit Account No. 033975. Charge any additional fees required by this paper or credit any overpayment in the mariner authorized above. A duplicate of this paper is attached.

Date

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Reg. No. 28872

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December 5, 2003

AMENDMENT

Hon. Commissioner-of-Patents Washington, D.C. 20231

Sir:

In response to the Office Action dated September 5, 2003, please amend this application as follows:

IN THE CLAIMS:

(Original) A method for performing a plasma-assisted treatment on a substrate in a reactor chamber, comprising:

introducing at least one process gas into the reactor chamber;

creating a plasma within the reactor chamber by establishing an RF electromagnetic field within the chamber and allowing the field to interact with the process gas; and

causing the electromagnetic field to have an energy level which varies cyclically between at least two values each sufficient to maintain the plasma, such that each energy level value is associated with performance of a respectively different treatment process on the substrate.